

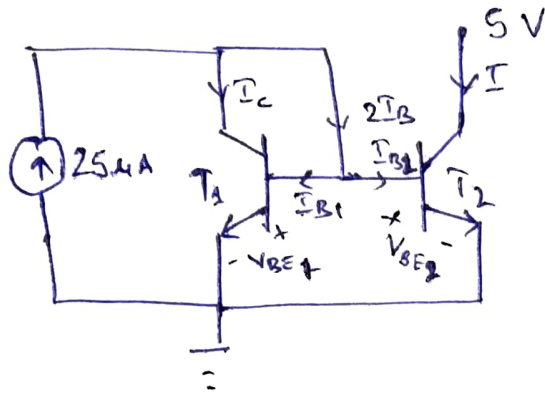
Name:

Roll no:

Test No.:

Subject : BEE + Analog Electronics
+ Electrical Materials.

1.(a)



Since both the transistors are identical

$$\therefore V_{BE1} = V_{BE2}$$

$$\& \hat{I}_{B1} = \hat{I}_{B2}$$

for transistor T_1

$$\hat{I}_C + 2\hat{I}_B = 25 \mu A$$

$$\text{as } \hat{I}_C = \beta \hat{I}_B = 25 \hat{I}_B$$

$$\hat{I}_B + 2 \times 25 \hat{I}_B = 25 \mu A$$

$$\hat{I}_B = \frac{25}{51} \mu A$$

$$\therefore I = \beta \hat{I}_B = 25 \times \frac{25}{51} \mu A$$

$$25 \hat{I}_B + 2 \hat{I}_B = 25 \mu A$$

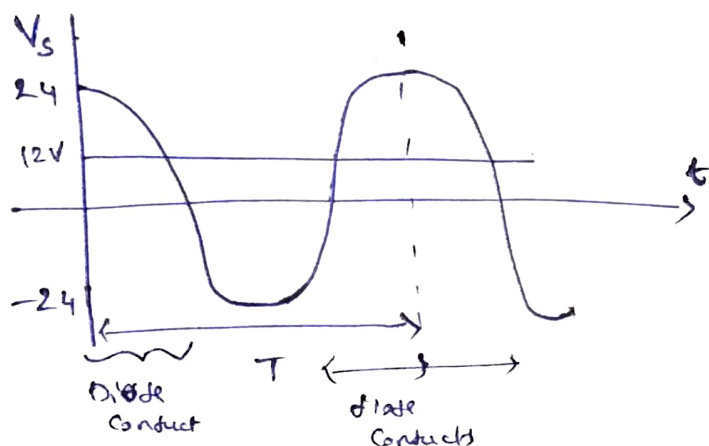
$$\hat{I}_B = \frac{25}{27} \mu A$$

$$\therefore \text{Current } I = \beta \hat{I}_B$$

$$= 25 \times \frac{25}{27} \mu A$$

$I = 23.148 \mu A$

1.6)



Conduction

$$\theta = \sin^{-1}\left(\frac{12}{24}\right) = \frac{\pi}{6}$$

$$\text{Conduction angle of diode} = \pi - 2\theta = \pi - \frac{2\pi}{6} = \frac{2\pi}{3}$$

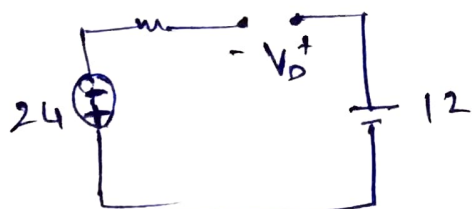
Fraction of each cycle during which diode conducts

$$\text{is } \frac{\frac{2\pi}{3}}{2\pi} = \frac{1}{3} \text{ of each cycle.}$$

$$\text{Peak value of diode current } (I_{PK}) = \frac{(V_s)_{\max} - 12}{100} = \frac{24 - 12}{100}$$

$$I_{PK} = 0.12 \text{ A}$$

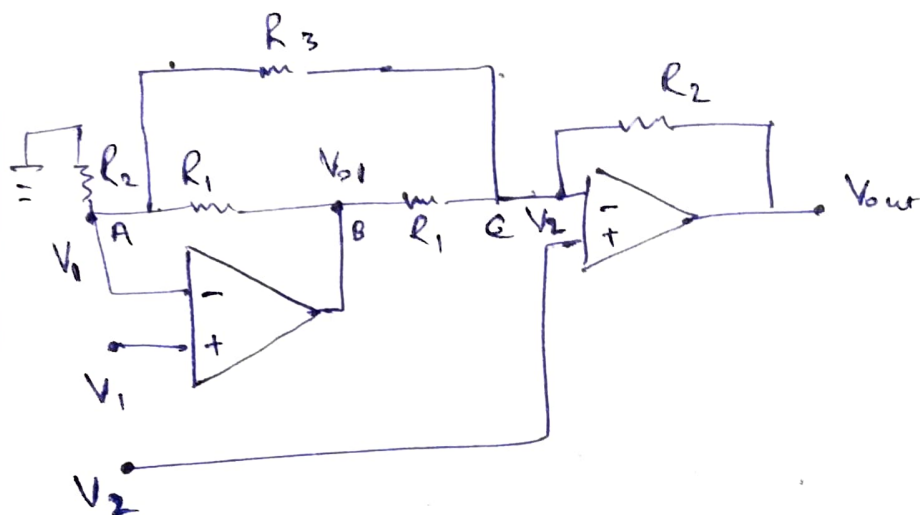
When Diode is off



$$V_D = 12 + (-V_s)_{\max} \\ = 12 + 24 = 36 \text{ V}$$

max. reverse bias voltage that appears across diode is $V_D = 36 \text{ V}$

1. (c)



By ~~virtual~~ Virtual ground Concept

$$V_C = V_2, \quad V_A = V_1$$

Now KCL at Node A

$$\frac{V_1}{R_2} + \frac{V_1 - V_2}{R_3} + \frac{V_1 - V_{01}}{R_1} = 0 \quad \text{--- (1)}$$

Now KCL at Node C

$$\frac{V_2 - V_1}{R_3} + \frac{V_2 - V_{01}}{R_1} + \frac{V_2 - V_{out}}{R_2} = 0 \quad \text{--- (2)}$$

Using (1) in (2)

$$\frac{V_1}{R_2} + \frac{V_1 - V_1}{R_1} + \frac{V_2 - V_{01}}{R_1} + \frac{V_2 - V_{out}}{R_2} = 0$$

$$\frac{V_1}{R_2} + \frac{V_1}{R_1} - \frac{2V_{01}}{R_1} + \frac{V_2}{R_2} - \frac{V_{out}}{R_2} + \frac{V_2}{R_1} = 0$$

$$\frac{V_1}{R_2} + \frac{V_1}{R_1} - \frac{2V_1}{R_2} - \frac{2V_1}{R_3} + \frac{2V_2}{R_3} - \frac{2V_1}{R_1} + \frac{V_2}{R_2} - \frac{V_{out}}{R_2} + \frac{V_2}{R_1} = 0$$

$$\frac{V_2 - V_1}{R_2} + \frac{V_2 - V_1}{R_1} + \frac{2(V_2 - V_1)}{R_3} = \frac{V_{out}}{R_2}$$

$$\therefore \left[\frac{V_{out}}{V_2 - V_1} = \left[1 + \frac{R_2}{R_1} + \frac{2 R_2}{R_3} \right] \right]$$

1.(d)

$$H_c = H_0 \left[1 - \left(\frac{T}{T_c} \right)^2 \right]$$

For $H_c = 1.6 \times 10^5 \text{ A/m}$ $T = 16 \text{ K}$

$$1.6 \times 10^5 = H_0 \left[1 - \left(\frac{16}{T_c} \right)^2 \right] \quad \text{--- (1)}$$

$$\& \quad 4 \times 10^5 = H_0 \left[1 - \left(\frac{14}{T_c} \right)^2 \right] \quad \text{--- (2)}$$

$$\frac{2.5 = \left[1 - \left(\frac{14}{T_c} \right)^2 \right]}{\left[1 - \left(\frac{16}{T_c} \right)^2 \right]} \Rightarrow 2.5 = \frac{T_c^2 - 14^2}{T_c^2 - 16^2}$$

$$2.5 T_c^2 - 640 = T_c^2 - 14^2$$

$$T_c^2 = 296 \Rightarrow \boxed{T_c = 17.2046 \text{ K}}$$

Critical temperature.
(transition temperature)

Using (1)

$$1.6 \times 10^5 = H_0 \left[1 - \left(\frac{16}{17.204} \right)^2 \right]$$

$$\boxed{H_0 = 1.184 \times 10^6 \text{ A/m}} \text{ is critical field at } 0 \text{ K}$$

At 4.2 K

$$H_c = 1.184 \times 10^6 \left[1 - \left(\frac{4.2}{17.2046} \right)^2 \right]$$

$$\boxed{H_c = 1.13 \times 10^6 \text{ A/m}}$$

1.e)

$$N = 10^{30} \text{ atoms/m}^3$$

$$T = 300 \text{ K}$$

$$\mu_m = 1.8 \times 10^{-23} \text{ A m}^2$$

[By Curie law]

$$\chi = \frac{N \mu_m^2}{K T}$$

$$= \frac{10^{30} \times (1.8 \times 10^{-23})^2 \times 4\pi \times 10^{-7}}{1.38 \times 10^{-23} \times 300}$$

$$\boxed{\chi = 0.0983} \rightarrow \text{Susceptibility of Paramagnetic material}$$

Now for dipole moment of bar

$$\text{Volume} = l \times \text{area of cross section}$$

$$= 0.12 \times 1 \times 10^{-4} = 1.2 \times 10^{-5} \text{ m}^3$$

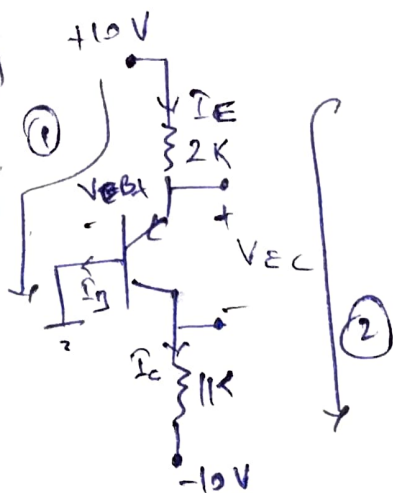
$$\text{Total number of atoms} = 10^{30} \times 1.2 \times 10^{-5} \\ = 1.2 \times 10^{25}$$

$$\text{Total dipole moment} = \mu_m \times \text{no. of atoms}$$

$$= 1.8 \times 10^{-23} \times 1.2 \times 10^{25}$$

$$= \underline{\underline{216 \text{ A m}^2}}$$

2. (a) (i)



Assuming the transistor in active region

$$V_{BE} = 0.7$$

KVL in loop 1

$$10 = I_E \times 2K + 0.7$$

$$I_E = 4.65 \text{ mA}$$

$$I_B = \frac{4.65}{1+\beta} = \frac{4.65}{101} \text{ mA}$$

$$I_E = I_E + I_B = 4.696 \text{ mA} = 4.694 \text{ mA}$$

KVL in loop 2

$$10 = 2K I_E + V_{EC} + 1K I_C - 10$$

$$20 = 2K \times 4.65 + V_{EC} + 1K \times 4.694$$

$$V_{EC} = 6.996 \text{ V}$$

$$V_{EC} > 0.2 \text{ V}$$

∴ Our assumption is correct transistor is in Active region.

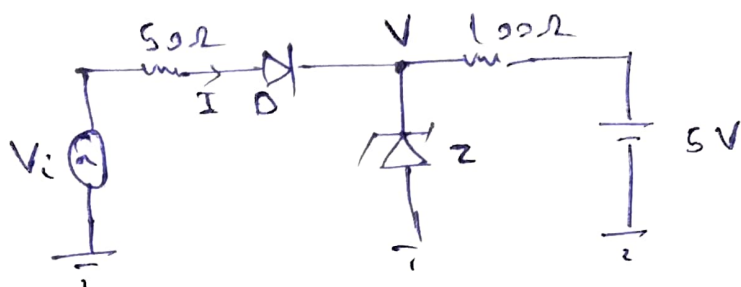
$I_E = 4.65 \text{ mA}$
$I_B = 46.04 \mu\text{A}$
$I_C = 4.694 \text{ mA}$

$V_B = 10 \text{ V}$
$V_E = 0.7 \text{ V}$

$$V_C = 4.694 \times 1K - 10$$

$V_C = -5.396 \text{ V}$

2(ii)



Assuming $D \rightarrow \text{ON}$, $Z \rightarrow \text{OFF}$

$$I = \frac{V_i - 5}{150}, \quad V = 5 + 100 \times I$$

So if $I > 0$, $V > 5V$ which will turn on the Zener diode and current through 100Ω resistor will become zero.

$$\text{as } V_Z = 5$$

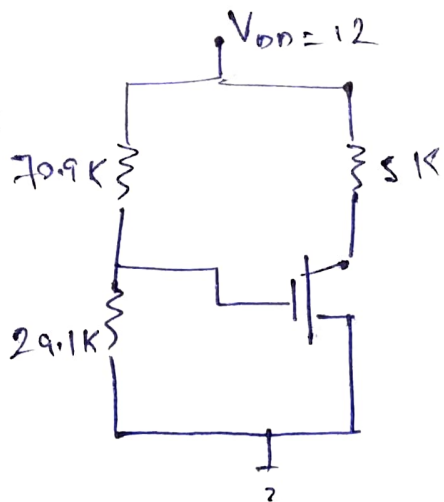
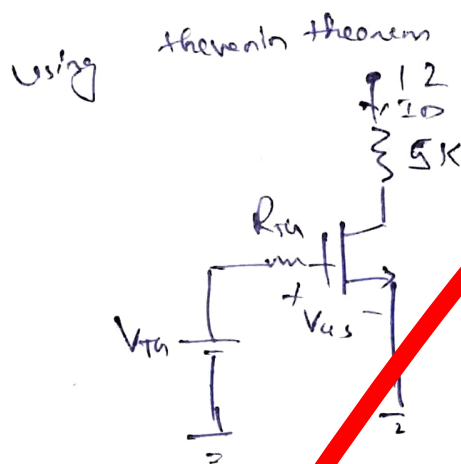
$$I = \frac{V_Z - 5}{100} = \frac{5 - 5}{100} = 0 \text{ A}$$

So, Power will be dissipated in 100Ω resistor when $Z \rightarrow \text{OFF}$ and $D \rightarrow \text{ON}$ and $V_i < 5V$. $V_i < 5$

But when $V_i < 5$, this will make diode 'D' reverse bias so current will not flow.

$\therefore$ Power dissipated in 100Ω resistor is Zero watts

26)

Dc AnalysisOpening all Capacitors [C_c] $\Rightarrow$ 

$$V_{TH} = \frac{12 \times 29.1 \text{ K}}{70.9 \text{ K} + 29.1 \text{ K}} = 3.492 \text{ V}$$

$$R_{TH} = 70.9 \text{ K} \parallel 29.1 \text{ K} = 20.6319 \text{ K}\Omega$$

As $I_{DQ} = 0$ $\therefore V_{GS} = V_{TH} = 3.492 \text{ V}$

$$I_{DQ} = K_n (V_{GS} - V_t)^2$$

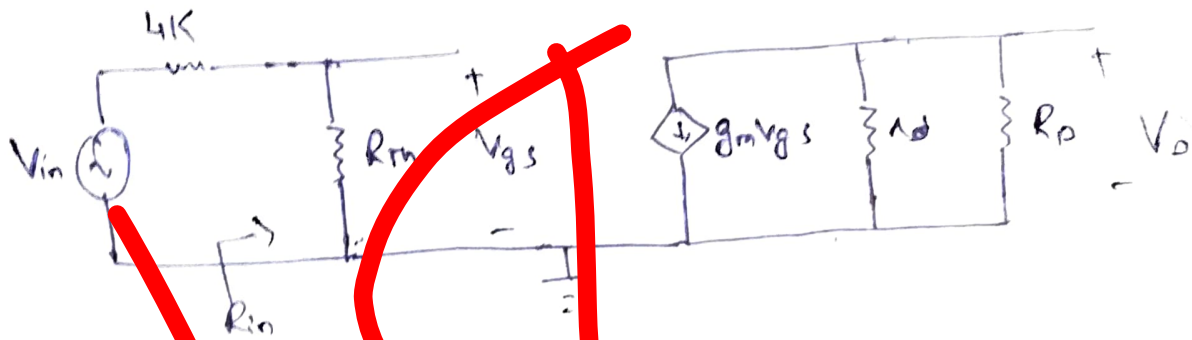
$$= 0.5 \times (3.492 - 1.5)^2 = 1.984 \text{ mA}$$

$$g_m = \frac{1}{1.1 I_{DQ}} = \frac{1}{0.01 \times 1.984} = 54.4 \text{ K}\Omega$$

$$g_m = \frac{\partial I_{DQ}}{\partial V_{GS}} = 2 K_n [V_{GS} - V_t] \times 1$$

$$= 2 \times 0.5 (3.492 - 1.5) = 1.992 \text{ mS}$$

AC equivalent circuit



$$V_{gs} = \frac{V_{in} \times R_m}{R_m + 4K} = \frac{V_{in} \times 20.6319K}{20.6319K + 4K}$$

$$V_{in} = 1.194 V_{gs}$$

$$V_o = -g_m V_{gs} [r_d \parallel R_o]$$

$$= -1.992 [34.4 \parallel 5] V_{gs} = -9.12 V_{gs}$$

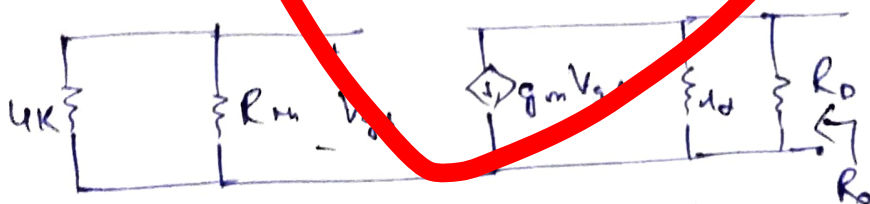
$$A_v = \frac{V_o}{V_{in}} = \frac{-9.12 V_{gs}}{1.194 V_{gs}}$$

$$A_v = -7.64$$

By seeing the circuit

$$R_{in} = R_m = 20.6319K\Omega$$

for output resistance (R_o)

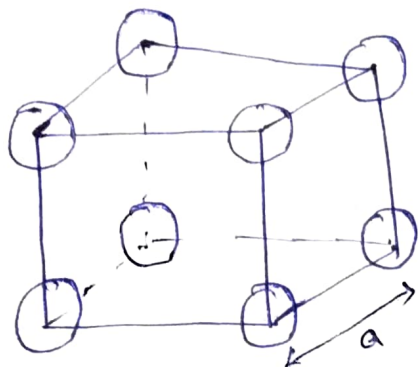


$V_{gs} = 0 \therefore$ current source gets open circuit

$$\therefore R_o = r_d \parallel R_o = [34.4 \parallel 5] K\Omega$$

$$R_o = 4.58K\Omega$$

2.(c) (i) Simple cube

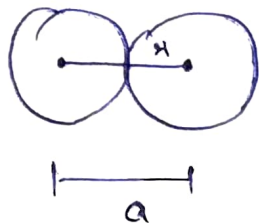


number of atoms

$$= \frac{1}{8} \times 8 = 1 \text{ atom}$$

Let radius of each atom be ' r '
and edge length of lattice be ' a '

Here



$$a = 2r \Rightarrow$$

$$r = \frac{a}{2}$$

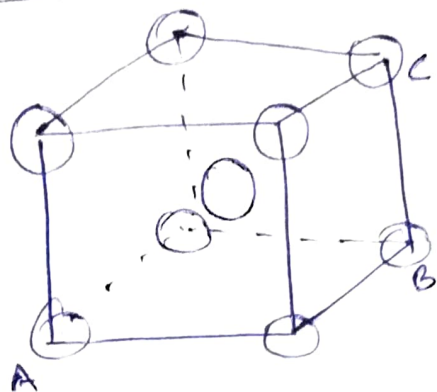
$$\text{APF (Atomic Packing Factor)} = \frac{\text{Volume of atoms/cell}}{\text{Volume of cell}}$$

$$= \frac{\text{no. of atom} \times \text{Volume of 1 atom}}{\text{Volume of cell}}$$

$$= \frac{1 \times \frac{4}{3} \pi r^3}{a^3} = \frac{\frac{4}{3} \pi \left(\frac{a}{2}\right)^3}{a^3}$$

$$\boxed{\begin{aligned} \text{APF} &= 0.5236 \\ &= 52.36\% \end{aligned}}$$

(ii)

Body Centred Cube

$$\text{no. of atoms} = \frac{1}{8} \times 8 + 1$$

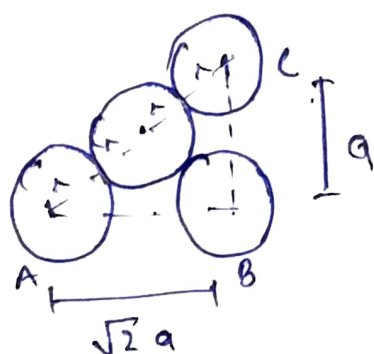
$$n = 2 \text{ atoms}$$

Here

$$(4r)^2 = (\sqrt{2}a)^2 + a^2$$

$$16r^2 = 3a^2$$

$$r = \frac{\sqrt{3}}{4} a$$

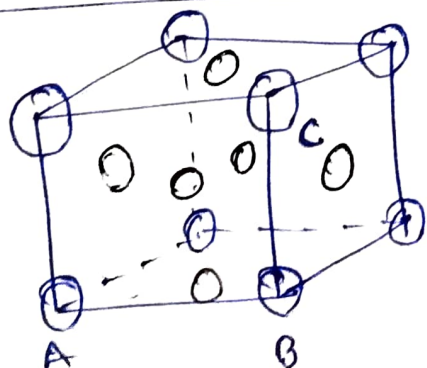


$$\text{APF} = \frac{n \times \frac{4}{3} \pi r^3}{a^3} = \frac{2 \times \frac{4}{3} \pi \left(\frac{\sqrt{3}}{4}\right)^3 \times a^3}{a^3}$$

$$\text{APF} = 0.6801$$

$$= 68.01\%$$

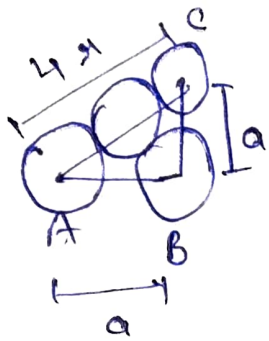
(iii)

Face Centred Cube

number of atoms

$$= \frac{1}{8} \times 8 + \frac{1}{2} \times 6$$

$$n = 4 \text{ atoms}$$



Here

$$(4r)^2 = a^2 + a^2$$

$$16r^2 = 2a^2$$

$$r = \frac{a}{2\sqrt{2}}$$

$$APF = \frac{n \times \frac{4}{3} \pi r^3}{a^3} = \frac{4 \times \frac{4}{3} \pi \times \left(\frac{1}{2\sqrt{2}}\right)^3 \times a^3}{a^3}$$

$$APF = 0.7405$$

$$= 74.05\%$$

(iv) Diamond Cube.

For this $r = \frac{\sqrt{3}}{8} a$

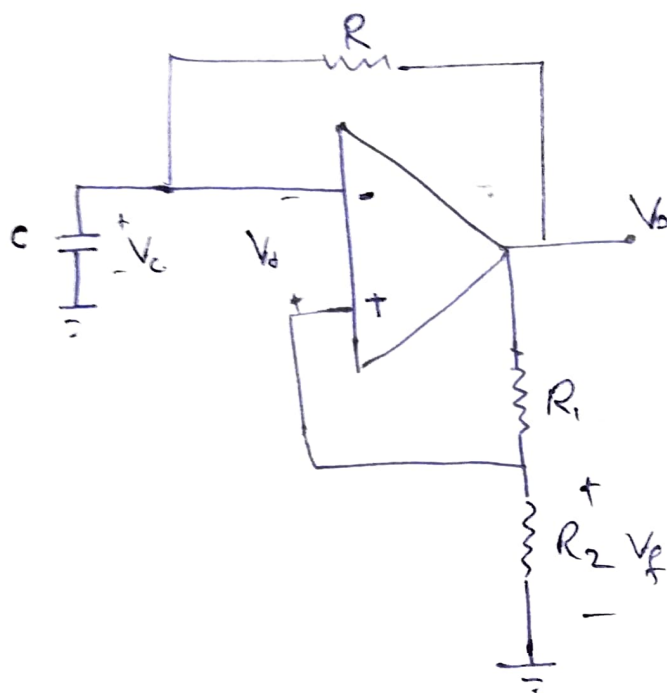
number of atoms $(n) = 8$

$$APF = \frac{n \times \frac{4}{3} \pi r^3}{a^3} = \frac{8 \times \frac{4}{3} \pi \times \left(\frac{\sqrt{3}}{8}\right)^3 \times a^3}{a^3}$$

$$APF = 0.34$$

$$= 34\%$$

3(a)

Astable Multivibrator

Assume $V_o = +V_{sat}$

$$V_p = V_o \left(\frac{R_2}{R_1 + R_2} \right) = \beta V_o = \beta V_{sat} \quad \left[\beta = \frac{R_2}{R_1 + R_2} \right]$$

and during this Capacitor starts charging through ~~the~~ R

$$V_o = V_p - V_c$$

When V_c reaches $+ \beta V_{sat}$, V_o becomes negative

and then $V_o = -V_{sat}$

$$V_p = -V_{sat} \times \left(\frac{R_2}{R_1 + R_2} \right) = -\beta V_{sat}$$

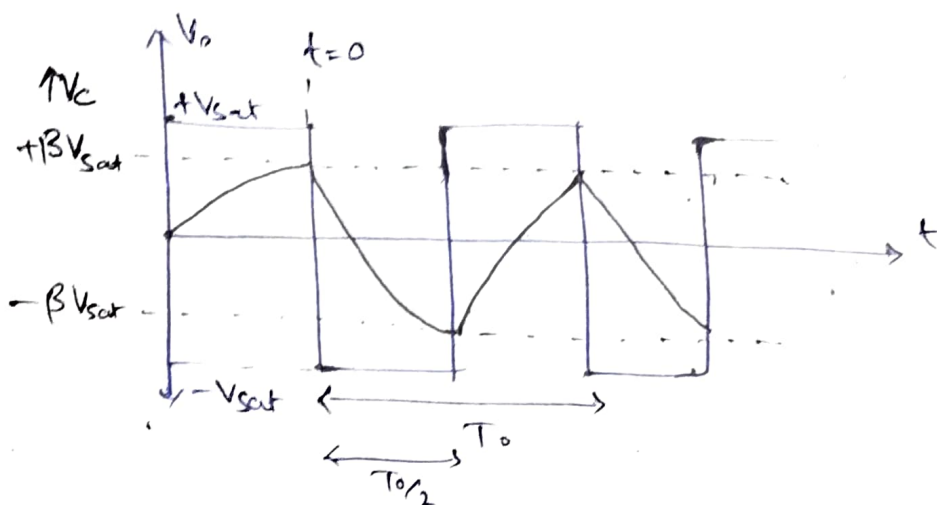
and Capacitor starts discharging through R

$$V_o = V_p - V_c = -\beta V_{sat} - V_c$$

When V_c becomes $- \beta V_{sat}$

V_o becomes ~~negative~~ positive

and V_o becomes $V_o = +V_{sat}$
and the cycle repeats.



for $t > 0$

$$V_c = -V_{sat} + [\beta V_{sat} + V_{sat}] e^{-t/\tau} \quad [\tau = RC]$$

At $t = T_o/2$

$$V_c = -\beta V_{sat}$$

$$-\beta V_{sat} = -V_{sat} + [\beta V_{sat} + V_{sat}] e^{-\frac{T_o}{2\tau}}$$

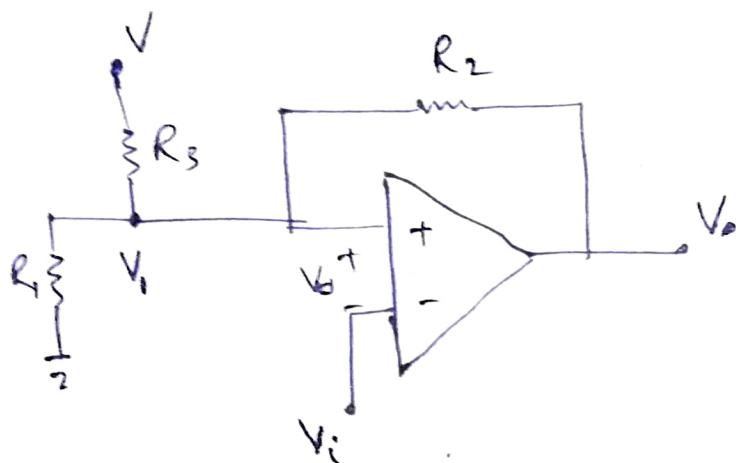
$$1 - \beta = (1 + \beta) e^{-T_o/2\tau}$$

Taking natural log on both sides

$$\ln\left(\frac{1-\beta}{1+\beta}\right) = -\left[\frac{T_o}{2\tau}\right] \Rightarrow T_o = 2\tau \ln\left(\frac{1+\beta}{1-\beta}\right)$$

$$T_o = 2RC \ln\left(\frac{1+\beta}{1-\beta}\right)$$

3.(b)



Applying KCL at V_1

$$\frac{V_1 - V}{R_3} + \frac{V_1}{R_1} + \frac{V_1 - V_0}{R_2} = 0$$

$$V_1 \left[\frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right] = \frac{V_0}{R_2} + \frac{V}{R_3}$$

$$V_1 = \frac{V_0 R_3 + V R_2}{R_2 R_3} \times \frac{[R_1 R_2 R_3]}{R_2 R_3 + R_1 R_2 + R_1 R_3}$$

$$V_1 = \frac{V_0 R_1 R_3 + V R_1 R_2}{R_1 R_2 + R_2 R_3 + R_3 R_1}$$

Now, Assume $V_0 = V^+$

$$V_0 = V_1 = V_i$$

When $V_i < V_1$ $V_d = +V_e$

& V_0 stays at V^+

When $V_i > V_1 \Rightarrow V_d$ becomes negative

$$V_0 = V^-$$

$$\therefore \boxed{V_{TH} = \frac{V^+ R_1 R_3 + V R_1 R_2}{R_1 R_2 + R_2 R_3 + R_3 R_1}}$$

3(b)

Assuming $V_o = V^-$

$$V_i = \frac{V^- R_1 R_3 + V R_1 R_2}{R_1 R_2 + R_2 R_3 + R_3 R_1}$$

$$V_o = V_i - V_i$$

When $V_i \gg V_i \Rightarrow V_o \Rightarrow \text{negative}$

$$V_o = V^-$$

Now when $V_i > V_i \Rightarrow V_o \Rightarrow \text{Positive}$

$$V_o = V^+$$

$$V_{TL} = V_i$$

$$\Rightarrow V_{TL} = \frac{V^- R_1 R_3 + V R_1 R_2}{R_1 R_2 + R_2 R_3 + R_3 R_1}$$

(ii)

$$V_{TL} = 4.9 \text{ V}, \quad V_{TH} = 5.1 \text{ V}$$

$$V_{TH} = \frac{13 \times 10K R_3 + 15 \times 10K R_2}{10K R_2 + R_2 R_3 + 10K R_3} = 5.1$$

$$130 R_3 + 150 R_2 - 51 R_2 - 51 R_3 = 5.1 R_2 R_3$$

$$79 R_2 + 99 R_3 = R_2 R_3 \quad \text{--- (1)}$$

$$V_{TL} = \frac{-13 \times 10K R_3 + 15 \times 10K R_2}{10K R_2 + R_2 R_3 + 10K R_3} = 4.9$$

$$101 R_2 - 179 R_3 = 49 R_2 R_3 \quad \text{--- (2)}$$

Solving (1) & (2)

$$R_3 = \frac{257}{13} K\Omega$$

$$= 19.77 K\Omega$$

$$R_2 = \frac{2570}{3} K\Omega$$

$$R_2 = 856.67 K\Omega$$

3. (c)

Crystal Imperfections

→ A crystal is formed when a unit cell is repeated such that every unit cell is surrounded by unit cells which are same as that of other unit cell and atoms are present on its lattice sites. But some times the position of atoms are dislocated from their natural or normal position which creates imperfection in crystal and this is known as Crystal imperfections.

These are classified on the basis of dimensions

- (i) Point defect [0-0]
- (ii) Line defect [1-0]
- (iii) Surface defect [2-0]
- (iv) Volumetric defect [3-0]

Point defect is due to the two types of missing of an atom from its lattice site.

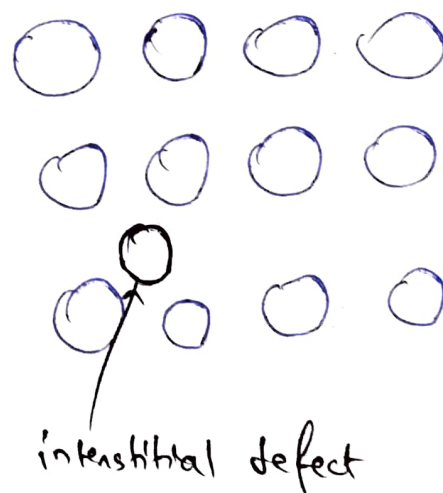
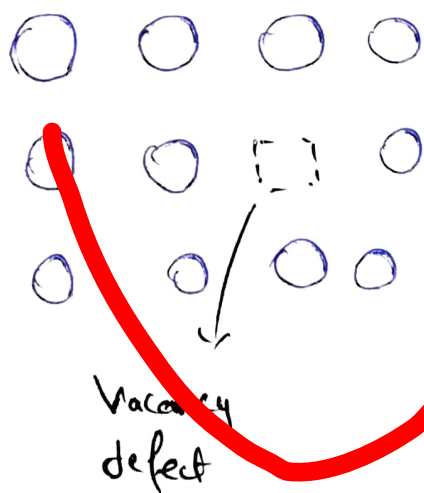
- (a) When the atom is not present in crystal creating a void or vacancy is known as Vacancy defect.

(b) when the atom is present in crystal but not at its original position. This is known as interstitial defect.

→ If these two defects occur in ionic crystal i.e., both cation and anion are not present in crystal then it is known as Schottky defect.

→ If cation is present ~~but~~ in between small spacing instead of its original position then it is known as Frenkel defect.

These defects generally occur in alkali halides.



Line defect

→ Edge dislocation & Screw dislocation

→ When extra half plane of atoms is inserted into the crystal lattice. This will increase the plasticity in material. This is known as Edge dislocation.

When one part of crystal is shifted relative to other part is known as Screw dislocation.

Surface defects may arise at boundary of between two grains i.e., small crystals in large crystal.

This may cause the rows of atoms may run in slightly different directions.

Volumetric defect:

These are 3D defect occur such as pores, cracks.

This may occur due to cluster of vacancies created in crystal, or a cluster of impurities present inside the crystal.

5(a)

$$m = 8$$

$$N_1 = 6$$

(i)

$$\text{Step size } (\alpha) = \frac{360^\circ}{m \times N_1} = \frac{360^\circ}{6 \times 8}$$

$$\boxed{\alpha = 7.5^\circ}$$

(ii)

$$\text{In one revolution } \Rightarrow \theta = 360^\circ$$

$$\text{number of step} = \frac{360^\circ}{\alpha} = \frac{360^\circ}{7.5}$$

$$\boxed{\text{Step/revolution} = 48}$$

(iii)

$$\text{As } f = 120 \text{ Hz}$$

~~in one revolution~~ ~~completes~~

$$\text{Steps/second} = \frac{f}{\text{Step/revolution}} = \frac{120}{48} = 2.5$$

$$\text{Speed} = 2.5 \times 60 = 150 \text{ rpm}$$

$$\boxed{N = 150 \text{ rpm}}$$

5.6)

(i)

$$N_s = \frac{120f}{P} = \frac{120 \times 50}{2} = 3000 \text{ rpm}$$

$$N = 2950 \text{ rpm}$$

$$S = \frac{N_s - N}{N_s} = \frac{3000 - 2950}{3000}$$

$$\boxed{S = 0.0167 \text{ pu} = 1.67 \%}$$

$$P_{out} = (1 - S) \cdot P_g = 15 \text{ kW}$$

$$P_g = \frac{15 \times 10^3}{1 - 0.0167} = 15.254 \text{ kW}$$

$$\text{Torque } (\tau) = \frac{P_g}{\omega_s} = \frac{15.254 \times 10^3 \times 60}{2\pi \times 3000}$$

$$\boxed{\tau = 48.555 \text{ Nm}}$$

Now when Torque is doubled.

$$\tau = 48.555 \times 2 = 97.11 \text{ Nm}$$

$$97.11 = \frac{15.254 \times 10^3 \times 60}{\omega}$$

$$\left[\tau = \frac{P_g}{\omega} \right]$$

Assuming Constant load
the speed becomes

$$\tau \propto \frac{P_g}{\omega}$$

So, doubling the torque,
Speed becomes half

$$\therefore N = \frac{2950}{2} \Rightarrow N = 1475$$

5(b)(iii)

$$\tau = 97.11$$

$$\tau \propto \frac{SV^2}{R_{zf}}$$

So for doubling the torque,

$$\text{Slip double, } \therefore S = 2 \times \frac{1}{60} = \frac{1}{30} = 0.033$$

$$P_{\text{out}} = N_s - N_s(1-s) = 3000 \times \left(1 - \frac{1}{30}\right)$$

$$N = 2900 \text{ rpm}$$

(iv)

$$P_{\text{out}} = P_g (1-s)$$

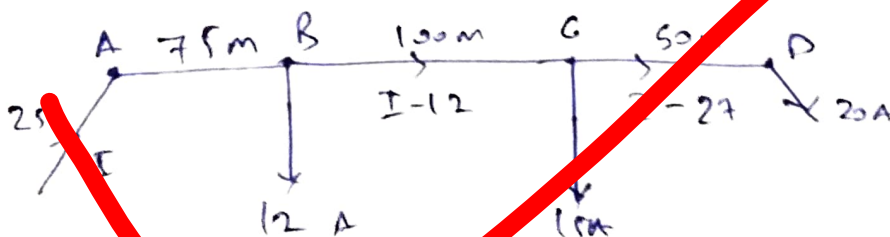
$$= 15.254 \times 10^3 \left(1 - \frac{1}{30}\right)$$

$$P_{\text{out}} = 14.74 \text{ kW}$$

5(c)

$$R = \frac{\rho l}{A} = \frac{1.78 \times 10^{-6} \times 10^{-2} \times 1}{0.27 \times 10^{-4}}$$

$$R = 6.5926 \times 10^{-4} \Omega/\text{m}$$



$$I = 27 + 20 \text{ A} \Rightarrow \underline{I = 47 \text{ A}}$$

- (i) Current in Section AB $\Rightarrow 47 \text{ A}$
Current in Section BC $\Rightarrow 47 - 12 = 35 \text{ A}$
Current in Section CD $\Rightarrow 20 \text{ A}$

(ii) Two Core resistance $= 2\mu' = 2 \times 6.5926 \times 10^{-4}$
 $= 1.318 \text{ m}\Omega/\text{m}$

(iii) $V_B = V_A - I \times (2\mu') \times 75$
 $= 250 - 47 \times 1.318 \times 10^{-3} \times 75$

$$\boxed{V_B = 245.354 \text{ V}}$$

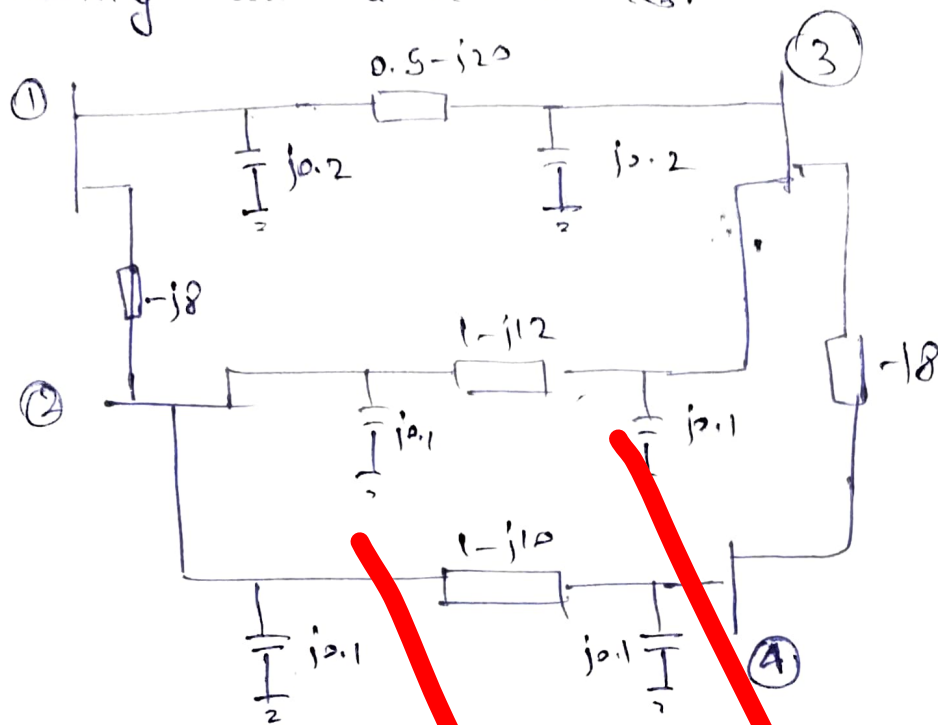
$$V_C = V_B - 35 \times (2\mu') \times 100$$
$$= 245.354 - 35 \times 1.318 \times 10^{-3} \times 100$$

$$\boxed{V_C = 240.74 \text{ V}}$$

$$V_D = V_C - 20 \times (2\mu') \times 50$$
$$= 240.74 - 20 \times 1.318 \times 10^{-3} \times 50$$

$$\boxed{V_D = 239.423 \text{ V}}$$

5(d) Deactivating all active sources.



Total admittance at bus ①

$$Y_{11} = -j8 + j0.2 + 0.5 - j20 = 0.5 - j27.8$$

at bus ②

$$Y_{22} = -j8 + j0.1 + j0.1 + 1 - j12 + 1 - j10 = 2 - j29.8$$

at bus ③

$$Y_{33} = 0.5 - j20 + j0.2 + j0.1 + 1 - j12 - j8 = 1.5 - j39.7$$

at bus ④

$$Y_{44} = 1 - j10 + j0.1 - j8 = 1 - j17.9$$

$$[Y]_{\text{Bus}} = \begin{bmatrix} 0.5 - j27.8 & j8 & -0.5 + j20 & 0 \\ j8 & 2 - j29.8 & -1 + j12 & -1 + j10 \\ -0.5 + j20 & -1 + j12 & 1.5 - j39.7 & j8 \\ 0 & -1 + j10 & j8 & 1.5 - j39.7 \end{bmatrix}$$

→
Bus
admittance
matrix

See)

Overhead System

- This System is suitable for every condition, i.e., for short transmission or long transmission but preferred for long transmission
- less problem of leakage current
- Insulation cost is lesser in this system as overhead line does not have insulation
- makes the system look complex and untidy
- Overhead line produces hissing noise
- This is less safe as fault may occur more frequently as it is in contact with surroundings.

Underground System

- only preferred for short transmission, due to high cost increment as length of underground cable increases.
- more leakage current when length increases
- High insulation cost as it has to stay underground and may be affected in underground condition & may leakage happens making undesirable condition
- make the system look beautiful as all the wiring is underground
- underground line are silent.
- This is more safe in terms of fault

Overhead line

- Require Space to erect the poles for transmission line and Right of way is also Considered
- Fault detection is easier in this system
- Preferred for High Voltage transmission
- Efficiency of this system is higher (generally)

Underground line

- ~~space~~ As it is underground so there is less problem of Space requirement
- Fault detection is ~~complex~~ difficult in underground system as it is not visible directly.
- Cannot be used for High Voltage transmission
- lower efficiency of the lines.

8.(a)

For Economic load Power dispatch

The increment fuel cost of all plants must be equal.

$$\therefore \lambda_1 = \lambda_2 = \lambda_3 = \lambda_4$$

$$0.012P_{g1} + 9 = 0.0096P_{g2} + 6 = 0.008P_{g3} + 8 \\ = 0.0068P_{g4} + 10 \quad \text{--- (1)}$$

Also, $P_{g1} + P_{g2} + P_{g3} + P_{g4} = 800 \text{ MW} \quad \text{--- (2)}$

Using (1)

~~0.012~~ $0.012P_{g1} + 9 - 0.0096P_{g2} - 6 = 0$

$$\Rightarrow P_{g2} = \frac{1}{0.0096} [0.012P_{g1} + 3] \quad \text{--- (3)}$$

$$P_{g3} = \frac{1}{0.008} [0.012P_{g1} + 4] \quad \text{--- (4)}$$

$$P_{g4} = \frac{1}{0.0068} [0.012P_{g1} - 1] \quad \text{--- (5)}$$

Using (3) (4) & (5) in (2)

$$P_{g1} \left[1 + \frac{0.012}{0.0096} + \frac{0.012}{0.008} + \frac{0.012}{0.0068} \right] + \frac{3}{0.0096} + \frac{1}{0.008} - \frac{1}{0.0068} \\ = 800$$

$$5.5147 P_{g1} = 509.56$$

$$\boxed{P_{g1} = 92.4 \text{ MW}}$$

$$P_{g2} = \frac{1}{0.0096} [0.042 \times 92.4 + 3] = \underline{428 \text{ MW}}$$

$$P_{g2} = \underline{428 \text{ MW}}$$

$$P_{g3} = \frac{1}{0.008} [0.012 \times 92.4 + 1] = \underline{263.6 \text{ MW}}$$

$$P_{g4} = \frac{1}{0.0068} [0.012 \times 92.4 - 1] = \underline{16 \text{ MW}}$$

$$P_{g2} = 428 \text{ MW}$$

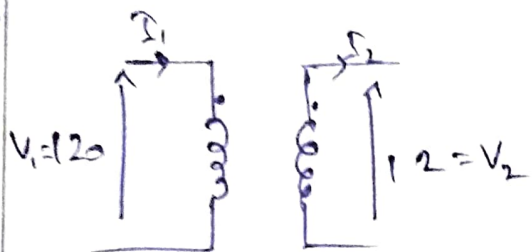
$$P_{g3} = 263.6 \text{ MW}$$

$$P_{g4} = 16 \text{ MW}$$

$$\lambda = 0.012 \times P_{g1} + 9 = 0.012 \times 92.4 + 9$$

$$\lambda = 10.1088 \text{ dollar/MWh}$$

8.6)

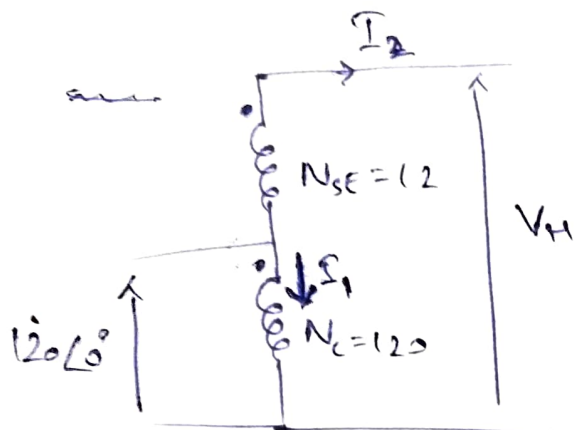


$$I_1 = \frac{S}{V_1} = \frac{100}{120} \text{ A}$$

$$I_2 = \frac{S}{V_2} = \frac{100}{12} \text{ A}$$

↓

(i)



$$V_H = 120 + 12$$

$$V_H = 132 \angle 0^\circ \text{ V}$$

↓
Secondary voltage of transformer.

(ii)

maximum VA rating in the auto

$$S_{\text{auto}} = V_H I_2$$

$$= 132 \times \frac{100}{12} = 1100 \text{ VA}$$

$$S_{\text{auto}} = 1100 \text{ VA}$$

(iii)

$$S_{\text{2wsg}} = 100 \text{ VA}$$

$$S_{\text{auto}} = 1100 \text{ VA}$$

$$\therefore \text{advantage in VA} = S_{\text{auto}} - S_{\text{2wsg}}$$

(S_{conductive})

$$S_{\text{conductive}} = 1100 - 100$$

$$= 1000 \text{ VA}$$

8(c)

$$P_{in} = \sqrt{3} \times V_L \times I_L \times \cos \phi$$

$$= \sqrt{3} \times 480 \times 60 \times 0.85 = 42400.6 \text{ Watts.}$$
$$= 42.4 \text{ KW}$$

$$\text{Stator losses} = \text{Copper loss} + \text{Stator Cu loss}$$

$$= 1800 + 2000 = 3800 \text{ W} = 3.8 \text{ KW}$$

(i)

$$P_{Ag} = P_{in} - \text{Stator loss} = 42.4 - 3.8$$

$$P_{Ag} = 38.6 \text{ KW}$$

(ii)

$$P_{conv} = P_{Ag} - \text{Rotor Cu loss} = 38.6 - 0.7$$

$$P_{conv} = 37.9 \text{ KW}$$

(iii)

$$P_{out} = P_{conv} - \text{friction and windage loss}$$

$$= 37.9 - 0.6$$

$$P_{out} = 37.3 \text{ KW}$$

(iv)

$$\eta = \frac{P_{out}}{P_{in}} \times 100 = \frac{37.3}{42.4} \times 100$$

$$\eta = 87.97 \%$$

8.(d)

$$N_s = \frac{120 f}{P} = \frac{120 \times 50}{6} = 1000 \text{ rpm}$$

$$S_m = \frac{N_s - N}{N_s} = \frac{1000 - 875}{1000} = 0.125 \text{ pu}$$

Slip at maximum torque,

(ii)

$$\frac{T}{T_{\max}} = \frac{2 S S_m}{S_m^2 + S^2}$$

$$\frac{T}{10} = \frac{2 \times 0.05 \times 0.125}{(0.05)^2 + (0.125)^2} = \frac{20}{29}$$

$$\text{Torque } (T) = \frac{20}{29} \times 10$$

$$T = 6.896 \text{ Nm}$$

(ii)

$$\frac{T_{st.}}{T_{\max}} = \frac{2 S_m}{S_m^2 + 1}$$

When external resistance is added S_m is changed.

$$\text{given } T_{st.} = 60\% T_{\max} = 0.6 T_{\max}$$

$$\frac{0.6 T_{\max}}{T_{\max}} = \frac{2 S_m}{S_m^2 + 1} \Rightarrow 0.6 S_m^2 - 2 S_m + 0.6 = 0$$

$$S_m = 3$$

~~neglected~~

$$S_m = \frac{1}{3} \checkmark$$

$$S_{m1} = 0.125$$

$$S_{m2} = \frac{1}{3}$$

$$S_{m1} = \frac{R'_2}{X'_2} \Rightarrow X'_2 = \frac{0.25}{0.125} = 2 \Omega$$

$$S_{m2} = \frac{[R'_2 + R_{ext.}]}{X'_2} \Rightarrow \frac{1}{3} = \frac{0.25 + R_{ext.}}{2}$$

$$R_{ext.} = 0.4167 \Omega$$

if we choose

$$S_{m2} = 3$$

$$\therefore 3 = \frac{[R'_2 + R_{ext.}]}{2} \Rightarrow R_{ext.} = 6 - 0.25$$

$$R_{ext.} = 5.75 \Omega$$

as here $S_{m2} = 3$ which is ~~in the~~ the
for ~~the~~ ~~plugging region~~ not desirable to get
maximum torque at this slip

So,

$R_{ext.} = 0.4167 \Omega$ is selected to
get 60% of max. torque at starting